NSN 5962-01-506-7265

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View Online at https://aerobasegroup.com/nsn/5962-01-506-7265
Body Length:
Between 0.850 inches and 0.930 inches
Body Width:
Between 0.240 inches and 0.295 inches
Body Height:
Between 0.160 inches and 0.180 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Used inf-15 an/apg-63 radar
Features Provided:
Electrostatic sensitive and hermetically sealed and monolithic and positive outputs and high speed and bipolar and programmed and
w/decoded output and 3-state output
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
12 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
85.00 nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Memory 1024 word x 4 bit
Test Data Document:
82577-932883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
18 printed circuit
Shelf Life:

Demilitarization: Yes - demil/mli

Unit Of Measure:

N/a

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